

Complementary power Darlingtons

Features

- Low collector-emitter saturation voltage
- Integrated antiparallel collector-emitter diode

Applications

- General purpose linear and switching

Description

The devices are manufactured in planar technology with “base island” layout and monolithic Darlingtons configuration. The resulting transistors show exceptional high gain performance coupled with very low saturation voltage.

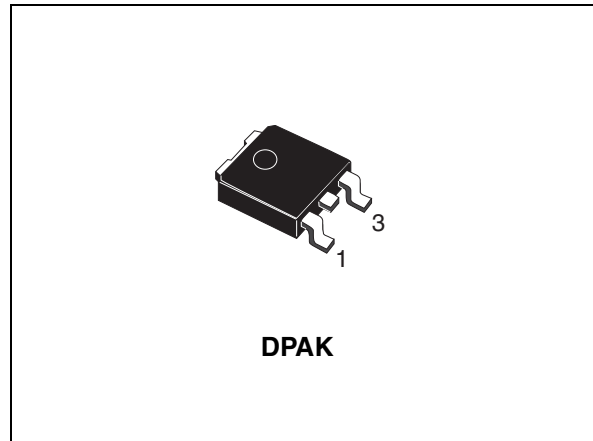


Figure 1. Internal schematic diagrams

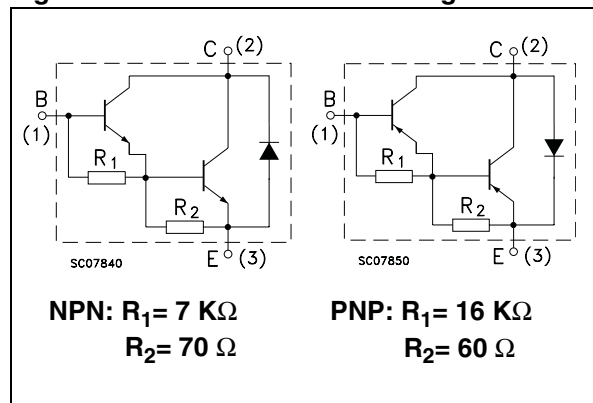


Table 1. Device summary

| Order codes | Marking | Polarity | Package | Packaging |
|-------------|---------|----------|---------|---------------|
| MJD122T4 | MJD122 | NPN | DPAK | Tape and reel |
| MJD127T4 | MJD127 | PNP | | |

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1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|-----------|--|------------|------------------|
| V_{CBO} | Collector-base voltage ($I_E = 0$) | 100 | V |
| V_{CEO} | Collector-emitter voltage ($I_B = 0$) | 100 | V |
| V_{EBO} | Emitter-base voltage ($I_C = 0$) | 5 | V |
| I_C | Collector current | 8 | A |
| I_{CM} | Collector peak current | 16 | A |
| I_B | Base current | 0.12 | A |
| P_{TOT} | Total dissipation at $T_{case} = 25^\circ\text{C}$ | 20 | W |
| T_{stg} | Storage temperature | -65 to 150 | $^\circ\text{C}$ |
| T_J | Max. operating junction temperature | 150 | $^\circ\text{C}$ |

Note: For PNP types voltage and current values are negative.

Table 3. Thermal data

| Symbol | Parameter | Value | Unit |
|-------------|---------------------------------------|-------|---------------------------|
| R_{thj-c} | Thermal resistance junction-case max. | 6.25 | $^\circ\text{C}/\text{W}$ |

2 Electrical characteristics

($T_{\text{case}} = 25\text{ °C}$; unless otherwise specified)

Table 4. Electrical characteristics

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------------------|--|--|-------------|------|--------|---------------|
| I_{CBO} | Collector cut-off current ($I_{\text{E}} = 0$) | $V_{\text{CB}} = 100\text{ V}$ | | - | 10 | μA |
| I_{CEO} | Collector cut-off current ($I_{\text{B}} = 0$) | $V_{\text{CE}} = 50\text{ V}$ | | - | 10 | μA |
| I_{EBO} | Emitter cut-off current ($I_{\text{C}} = 0$) | $V_{\text{EB}} = 5\text{ V}$ | | - | 2 | mA |
| $V_{\text{CEO(sus)}}^{(1)}$ | Collector-emitter sustaining voltage ($I_{\text{B}} = 0$) | $I_{\text{C}} = 30\text{ mA}$ | 100 | - | | V |
| $V_{\text{CE(sat)}}^{(1)}$ | Collector-emitter saturation voltage | $I_{\text{C}} = 4\text{ A}$ $I_{\text{B}} = 16\text{ mA}$ $I_{\text{C}} = 8\text{ A}$ $I_{\text{B}} = 80\text{ mA}$ | | - | 2 4 | V V |
| $V_{\text{BE(sat)}}^{(1)}$ | Base-emitter saturation voltage | $I_{\text{C}} = 8\text{ A}$ $I_{\text{B}} = 80\text{ mA}$ | | - | 4.5 | V |
| $V_{\text{BE(on)}}^{(1)}$ | Base-emitter on voltage | $I_{\text{C}} = 4\text{ A}$ $V_{\text{CE}} = 4\text{ V}$ | | - | 2.8 | V |
| $h_{\text{FE}}^{(1)}$ | DC current gain | $I_{\text{C}} = 4\text{ A}$ $V_{\text{CE}} = 4\text{ V}$ $I_{\text{C}} = 8\text{ A}$ $V_{\text{CE}} = 4\text{ V}$ | 1000 100 | - | 12000 | |

1. Pulsed duration = 300 μs , duty cycle $\leq 1.5\%$

Note: For PNP types voltage and current values are negative.

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

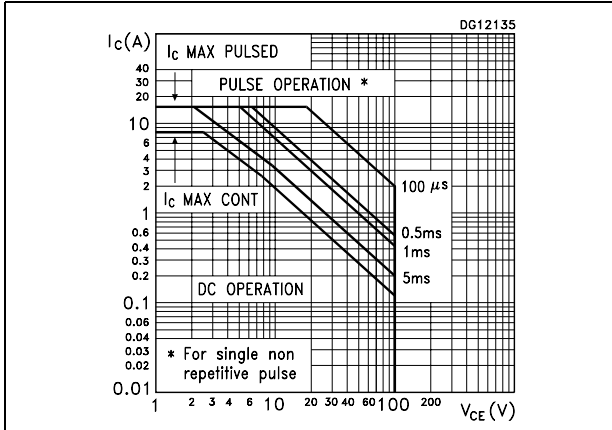


Figure 3. Derating curve

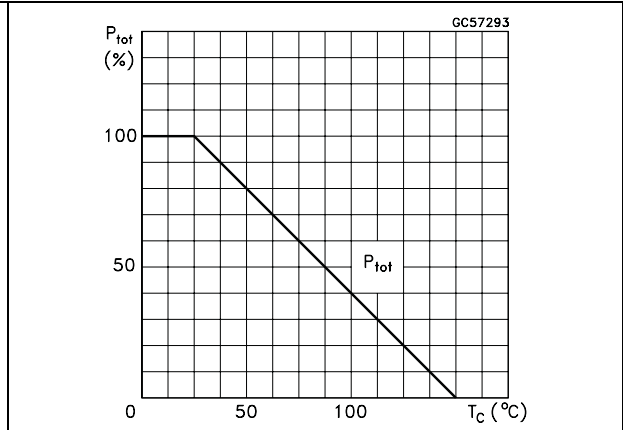


Figure 4. DC current gain for NPN type

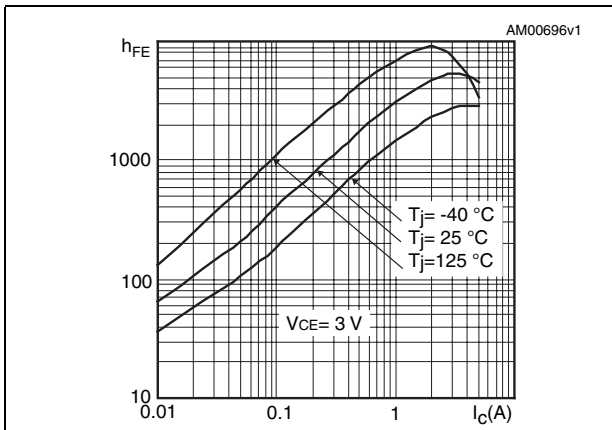


Figure 5. DC current gain for PNP type

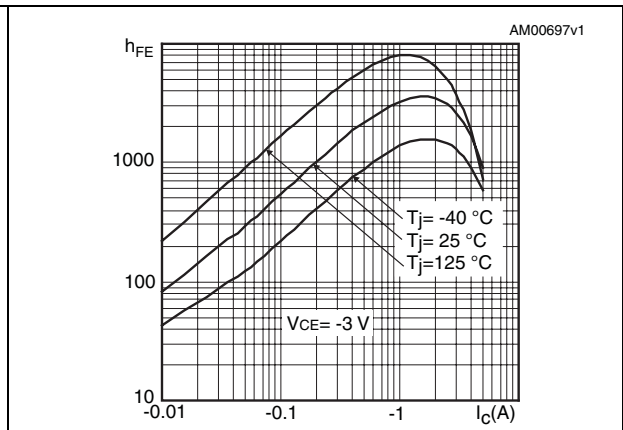


Figure 6. Collector-emitter saturation voltage for NPN type



Figure 7. Collector-emitter saturation voltage for PNP type

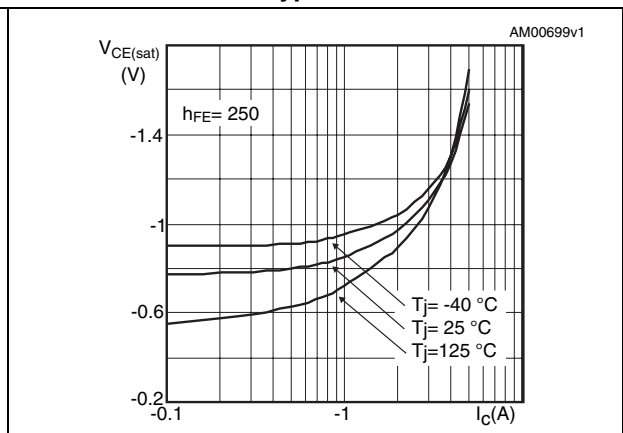


Figure 8. Base-emitter saturation voltage for NPN type



Figure 9. Base-emitter saturation voltage for PNP type



Figure 10. Base-emitter on voltage for NPN type



Figure 11. Base-emitter on voltage for PNP type



Figure 12. Resistive load switching times for NPN type (on)



Figure 13. Resistive load switching times for PNP type (on)



Figure 14. Resistive load switching times for NPN type (off)



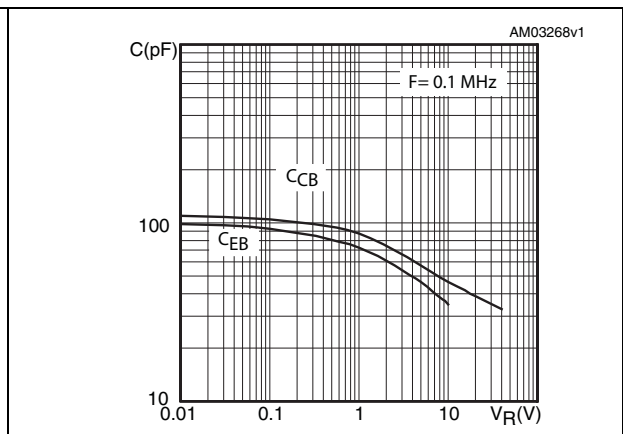
Figure 15. Resistive load switching times for PNP type (off)



Figure 16. Capacitances for NPN type



Figure 17. Capacitances for PNP type



3 Test circuits

Figure 18. Resistive load switching for NPN type



- 1. Fast electronic switch
- 2. Non-inductive resistor

Figure 19. Resistive load switching for PNP type



- 1. Fast electronic switch
- 2. Non-inductive resistor

4 Package mechanical data

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TO-252 (DPAK) mechanical data

| DIM. | mm. | | |
|------|------|------|-------|
| | min. | typ | max. |
| A | 2.20 | | 2.40 |
| A1 | 0.90 | | 1.10 |
| A2 | 0.03 | | 0.23 |
| b | 0.64 | | 0.90 |
| b4 | 5.20 | | 5.40 |
| c | 0.45 | | 0.60 |
| c2 | 0.48 | | 0.60 |
| D | 6.00 | | 6.20 |
| D1 | | 5.10 | |
| E | 6.40 | | 6.60 |
| E1 | | 4.70 | |
| e | | 2.28 | |
| e1 | 4.40 | | 4.60 |
| H | 9.35 | | 10.10 |
| L | 1 | | |
| L1 | | 2.80 | |
| L2 | | 0.80 | |
| L4 | 0.60 | | 1 |
| R | | 0.20 | |
| V2 | 0° | | 8° |



5 Revision history

Table 5. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 01-Aug-2002 | 8 | |
| 01-Oct-2007 | 9 | Collector current limits have been improved |
| 03-Oct-2007 | 10 | Package mechanical data updated |
| 21-Apr-2009 | 11 | The device MJD127 has been inserted Section 2.1: Electrical characteristics (curves) has been updated |

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